# NSN 5961-01-069-4505

Transistor - Page 1 of 1



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## Inclosure Material:

Metal

## **Overall Length:**

Between 0.250 inches and 0.450 inches

## **Overall Diameter:**

0.875 inches

## **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-3

Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

Features Provided:

Hermetically sealed case and mounting hardware

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

45.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

Between 5.00 amperes source cutoff current and 12.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

100.0 watts small-signal input power, common-collector

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

1 case and 2 pin

#### **Specification Data:**

80131-release6595 professional/industrial association specification

## Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

No

## Fiig:

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